NSN 5961-01-466-0397

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Diode Semiconductor Device - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-466-0397 **Inclosure Material:** Metal **Overall Length:** 4.250 inches **Terminal Length:** 2.600 millimeters **Overall Width:** 1.600 inches **End Application:** General purpose electronic test equipment **Mounting Facility Quantity: Mounting Method: Terminal Semiconductor Material:** Silicon **Voltage Rating In Volts Per Characteristic:** 50.0 breakdown voltage, collector to emitter, sustained and 60.0 breakdown voltage, collector-to-base, emitter open **Current Rating Per Characteristic:** 700.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 2.0 watts small-signal output power, common-base preset **Maximum Operating Tempurature Per Measurement Point:** -65.0 degrees celsius case and 150.0 degrees celsius case **Terminal Type And Quantity:** 3 uninsulated wire lead Shelf Life: N/a **Unit Of Measure: Demilitarization:** No Fiig: